

#### VCXO-TO-LVCMOS OUTPUTS

ICS810061

#### GENERAL DESCRIPTION



The ICS81006I is a high performance, low jitter/ low phase noise VCXO and is a member of the HiPerClockS<sup>TM</sup> family of high performance clock solutions from IDT. The ICS81006I works in conjunction with a pullable crystal to generate

an output clock over the range of 12MHz - 31.25MHz and has 6 LVCMOS outputs, effectively integrating a fanout buffer function.

The frequency of the VCXO is adjusted by the VC control voltage input. The output range is  $\pm 100$ ppm around the nominal crystal frequency. The VC control voltage range is 0 -  $V_{DD}$ . The device is packaged in a small 4mm x 4mm VFQFN package and is ideal for use on space constrained boards typically encountered in ADSL/VDSL applications.

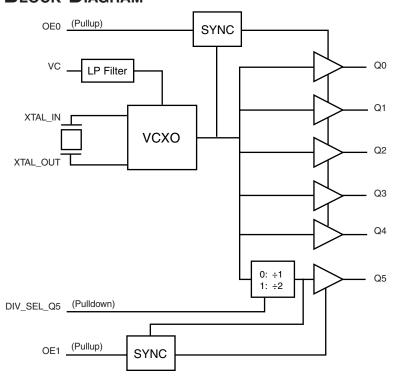
#### **F**EATURES

- Six LVCMOS/LVTTL outputs,  $20\Omega$  nominal output impedance
- Output Q5 can be selected for ÷1 or ÷2 frequency relative to the crystal frequency
- Output frequency range: 12MHz to 31.25MHz
- Crystal pull range: ± 90ppm (typical)
- Synchronous output enable places outputs in High-Impedance state
- On-chip filter on VIN to suppress noise modulation of VCXO
- $\bullet$   $V_{DD}/V_{DDO}$  combinations
  - 3.3V/3.3V
  - 3.3V/2.5V
  - 3.3V/1.8V
  - 2.5V/2.5V
  - 2.5V/1.8V

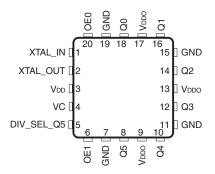
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- 4mm x 4mm 20 Lead VFQFN package is ideal for space constrained designs
- -40°C to 85°C ambient operating temperature
- Available in both standard (RoHS 5) and lead-free (RoHS 6) packages

### **BLOCK DIAGRAM**



# PIN ASSIGNMENT



# ICS81006I 20-Lead VFQFN 4mm x 4mm x 0.925 package body K Package Top View

TABLE 1. PIN DESCRIPTIONS

Number	Name	Т	уре	Description
1, 2	XTAL_IN, XTAL_OUT	Input		Crystal oscillator interface. XTAL_IN is the input. XTAL_OUT is the output.
3	$V_{_{\mathrm{DD}}}$	Power		Positive supply pin.
4	VC	Input		Control voltage input.
5	DIV_SEL_Q5	Input	Pulldown	Output divider select pin for Q5 output. When LOW, ÷1. When HIGH, ÷2. LVCMOS/LVTTL interface levels.
6	OE1	Input	Pullup	Output enable pin. When HIGH, Q5 output is enabled. When LOW, forces Q5 to a high impedance state. LVCMOS/LVTTL interface levels.
7, 11, 15, 19	GND	Power		Power supply ground.
8, 10, 12, 14, 16, 18	Q5, Q4, Q3, Q2, Q1, Q0	Output		Single-ended clock outputs. LVCMOS/LVTTL interface levels. 20Ω output impedance.
9, 13, 17	$V_{\scriptscriptstyle DDO}$	Power		Output supply pins.
20	OE0	Input	Pullup	Output enable pin. When HIGH, Q0:Q4 outputs are enabled. When LOW, forces Q0:Q4 to a high impedance state. LVCMOS/LVTTL interface levels.

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance	OE0, OE1			4		pF
			$V_{DD} = V_{DDO} = 3.465V$			3	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{DD} = 3.465V \text{ or } 2.625V,$ $V_{DDO} = 2.625V$			4	pF	
			$V_{DD} = 3.465V \text{ or } 2.625V,$ $V_{DDO} = 2V$			6	pF
R <sub>PULLUP</sub>	Input Pullup Resistor				51		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resi	stor			51		kΩ
			$V_{DDO} = 3.3V$			20	Ω
R <sub>OUT</sub>			V <sub>DDO</sub> = 2.5V			25	Ω
			V <sub>DDO</sub> = 1.8V			38	Ω

#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage, V<sub>DD</sub> 4.6V

Inputs,  $V_{I}$  -0.5V to  $V_{DD}$  + 0.5 V

Outputs,  $V_{O}$  -0.5V to  $V_{DD}$  + 0.5V

Package Thermal Impedance,  $\theta_{_{JA}}~60.4^{\circ}\text{C/W}$  (0 mps)

Storage Temperature,  $T_{STG}$  -65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

 $\textbf{TABLE 3A. Power Supply DC Characteristics, } V_{\text{DD}} = 3.3 \text{V} \pm 5\%, V_{\text{DDO}} = 3.3 \text{V} \pm 5\% = 2.5 \text{V} \pm 5\% = 1.8 \text{V} \pm 0.2 \text{V}, \text{TA} = -40 ^{\circ}\text{C} \text{ to } 85 ^{\circ}\text{C}$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Positive Supply Voltage		3.135	3.3	3.465	V
			3.135	3.3	3.465	V
V <sub>DDO</sub>	Output Supply Voltage		2.375	2.5	2.625	V
			1.6	1.8	2.0	V
I <sub>DD</sub>	Power Supply Current				50	mA
I <sub>DDO</sub>	Output Supply Current				20	mA

 $\textbf{TABLE 3B. Power Supply DC Characteristics, } V_{DD} = 2.5V \pm 5\%, V_{DDO} = 2.5V \pm 5\% = 1.8V \pm 0.2V, TA = -40^{\circ}C \text{ to } 85^{\circ}C$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Positive Supply Voltage		2.375	2.5	2.625	V
V <sub>DDO</sub>	Output Supply Voltage		2.375	2.5	2.625	V
			1.6	1.8	2.0	V
I <sub>DD</sub>	Power Supply Current				50	mA
I <sub>DDO</sub>	Output Supply Current				20	mA

TABLE 3C. LVCMOS/LVTTL DC CHARACTERISTICS, TA = -40°C TO 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
\/	Input High Voltage		$V_{DD} = 3.3V \pm 5\%$	2		$V_{DD} + 0.3$	V
V <sub>IH</sub>	Input High Voltage		$V_{DD} = 2.5V \pm 5\%$	1.7		V <sub>DD</sub> + 0.3	V
\/	Input Low Voltogo	OE0, OE1,	$V_{DD} = 3.3V \pm 5\%$	-0.3		0.8	V
V <sub>IL</sub>	Input Low Voltage	DIV_SEL_Q5	$V_{DD} = 2.5V \pm 5\%$	-0.3		0.7	V
VC	VCXO Control Volta	age		0		V <sub>DD</sub>	V
	Input High Current	DIV_SEL_Q5	$V_{DD} = 3.3V \text{ or } 2.5V \pm 5\%$			150	μΑ
IH	Input High Current	OE0, OE1	$V_{DD} = 3.3V \text{ or } 2.5V \pm 5\%$			5	μΑ
	Input Low Current	DIV_SEL_Q5	$V_{DD} = 3.3V \text{ or } 2.5V \pm 5\%$	-5			μΑ
I I <sub>IL</sub>	Imput Low Current	OE0, OE1	$V_{DD} = 3.3V \text{ or } 2.5V \pm 5\%$	-150			μΑ
I,	Input Current of VC	pin	$V_{DD} = 3.465 V \text{ or } 2.625 V$	-100		100	μΑ
			$V_{DDO} = 3.3V \pm 5\%$	2.6			V
V <sub>OH</sub>	Output High Voltage	e;NOTE 1	$V_{DDO} = 2.5V \pm 5\%$	1.8			V
			$V_{DDO} = 1.8V \pm 0.2V$	1.5			٧
\ <u></u>	Output Low Voltage	·NOTE 1	$V_{DDO} = 3.3V \text{ or } 2.5V \pm 5\%$			0.5	٧
V <sub>OL</sub>	V <sub>oL</sub> Output Low Voltage;NC		$V_{DDO} = 1.8V \pm 0.2V$			0.4	V

NOTE 1: Outputs terminated with  $50\Omega$  to  $V_{DDO}/2$ . See Parameter Measurement section, "Load Test Circuit" diagrams.

Table 4A. AC Characteristics,  $V_{DD} = V_{DDO} = 3.3V \pm 5\%$ , Ta = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f <sub>out</sub>	Output Frequency			12	19.44	31.25	MHz
<i>t</i> jit(Ø)	RMS Phase Jitter (Random); NOTE 1		Integration Range: 1kHz- 1MHz		0.35		ps
t-1-(-)	Output Skew; NOTE 2, 3	Q0:Q4				30	ps
tsk(o)		Q0:Q5	DIV_SEL_Q5 = ÷1			100	ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time		20% to 80%	200		750	ps
odc	Output Duty Cycle			44		56	%

NOTE 1: Please refer to the Phase Noise Plot.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential cross points.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 4B. AC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ , Ta = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f <sub>out</sub>	Output Frequency			12	19.44	31.25	MHz
<i>t</i> jit(Ø)	RMS Phase Jitter (Random); NOTE 1		Integration Range: 1kHz- 1MHz		0.38		ps
tol(a)	Output Okew,	Q0:Q4				20	ps
tsk(o)		Q0:Q5	DIV_SEL_Q5 = ÷1			90	ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time		20% to 80%	300		800	ps
odc	Output Duty Cycle			45		55	%

NOTE 1: Please refer to the Phase Noise Plot.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential cross points.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 4C. AC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ ,  $V_{DDO} = 1.8V \pm 0.2V$ , Ta = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f <sub>out</sub>	Output Frequency			12	19.44	31.25	MHz
tjit(Ø)	RMS Phase Jitter (Random); NOTE 1		Integration Range: 1kHz-1MHz		0.27		ps
tal(a)	Output Skew;	Q0:Q4				50	ps
tsk(o)	NOTE 2, 3 Q0:Q		DIV_SEL_Q5 = ÷1			180	ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time		20% to 80%	450		1400	ps
odc	Output Duty Cycle			45		55	%

NOTE 1: Please refer to the Phase Noise Plot.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential cross points.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 4D. AC Characteristics,  $V_{DD} = V_{DDO} = 2.5V \pm 5\%$ , Ta = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f <sub>out</sub>	Output Frequency			12	19.44	31.25	MHz
<i>t</i> jit(Ø)	RMS Phase Jitter (Random); NOTE 1		Integration Range: 1kHz-1MHz		0.28		ps
tsk(o)	Odipat Okew,	Q0:Q4				25	ps
isk(0)		Q0:Q5	DIV_SEL_Q5 = ÷1			105	ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time		20% to 80%	300		800	ps
odc	Output Duty Cycle			45		55	%

NOTE 1: Please refer to the Phase Noise Plot.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential cross points.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 4E. AC Characteristics,  $V_{DD} = 2.5V \pm 5\%$ ,  $V_{DDO} = 1.8V \pm 0.2V$ , Ta = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f <sub>out</sub>	Output Frequency			12	19.44	31.25	MHz
<i>t</i> jit(Ø)	RMS Phase Jitter (Random); NOTE 1		Integration Range: 1kHz-1MHz		0.26		ps
tol(a)	Output Onew,	Q0:Q4				40	ps
tsk(o)		Q0:Q5	DIV_SEL_Q5 = ÷1			185	ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time		20% to 80%	450		1400	ps
odc	Output Duty Cycle			40		60	%

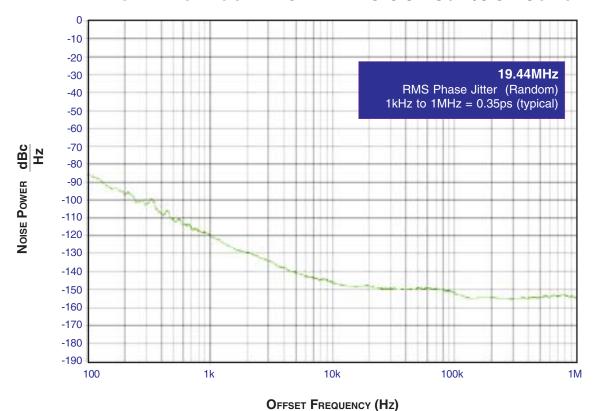
NOTE 1: Please refer to the Phase Noise Plot.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions.

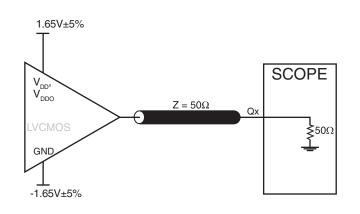
Measured at the output differential cross points.

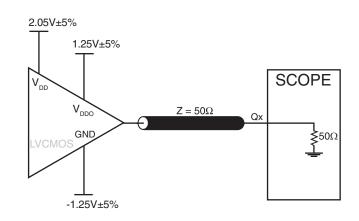
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Typical Phase Noise at 19.44MHz @ 3.3V Core/3.3V Output



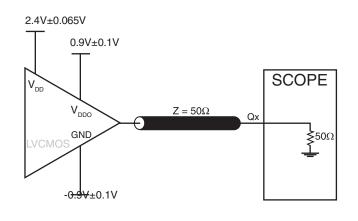
## PARAMETER MEASUREMENT INFORMATION

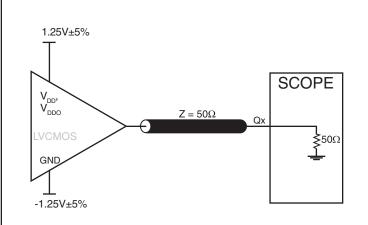




#### 3.3V CORE/3.3V OUTPUT LOAD AC TEST CIRCUIT

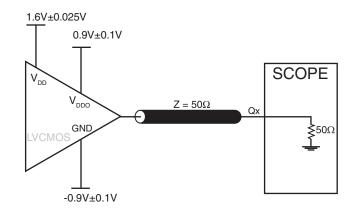
3.3V Core/2.5V OUTPUT LOAD AC TEST CIRCUIT

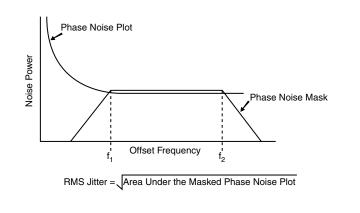




#### 3.3V CORE/1.8V OUTPUT LOAD AC TEST CIRCUIT

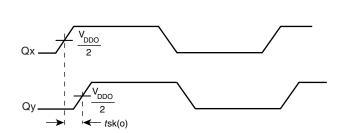
2.5V CORE/2.5V OUTPUT LOAD AC TEST CIRCUIT

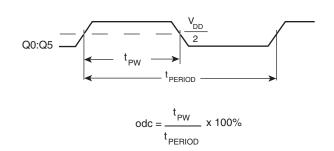




2.5 Core/1.8V Output Load AC Test Circuit

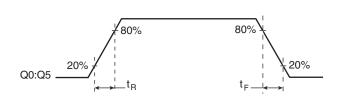
**RMS PHASE JITTER** 





#### **OUTPUT SKEW**

#### OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD



#### OUTPUT RISE/FALL TIME

## **APPLICATION INFORMATION**

#### VCXO CRYSTAL SELECTION

Choosing a crystal with the correct characteristics is one of the most critical steps in using a Voltage Controlled Crystal Oscillator (VCXO). The crystal parameters affect the tuning range and

accuracy of a VCXO. Below are the key variables and an example of using the crystal parameters to calculate the tuning range of the VCXO.

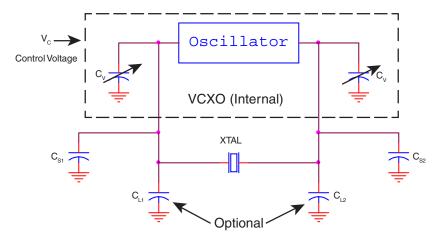


FIGURE 1: VCXO OSCILLATOR CIRCUIT

- V<sub>c</sub> Control voltage used to tune frequency
- $\mathrm{C_v}$  Varactor capacitance, varies due to the change in control voltage
- C<sub>L1,</sub> C<sub>L2</sub> Load tuning capacitance used for fine tuning or centering nominal frequency
- $C_{\rm S1,}\,C_{\rm S2}$  Stray Capacitance caused by pads, vias, and other board parasitics

TABLE 5. EXAMPLE CRYSTAL PARAMETERS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>N</sub>	Nominal Frequency			19.44		MHz
f <sub>T</sub>	Frequency Tolerance				±20	ppm
f <sub>s</sub>	Frequency Stability				±20	ppm
	Operating Temperature Range		0		70	°C
C <sub>L</sub>	Load Capacitance			12		pF
C <sub>o</sub>	Shunt Capacitance			4		рF
C <sub>0,</sub> C <sub>1</sub>	Pullability Ratio			220	240	
ESR	Equivalent Series Resistance				20	
	Drive Level				1	mW
	Aging @ 25°C		±3 per year			ppm
	Mode of Operation		F	undament	al	

#### Table 6. Varactor Parameters

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>v_Low</sub>	Low Varactor Capacitance	$V_C = 0V$		15.4		pF
$C_{V\_HIGH}$	High Varactor Capacitance	$V_{\rm C} = 3.3V$		29.6		pF

#### **F**ORMULAS

$$C_{Low} = \frac{\left(C_{L1} + C_{S1} + C_{V_{\_Low}}\right) \cdot \left(C_{L2} + C_{S2} + C_{V_{\_Low}}\right)}{\left(C_{L1} + C_{S1} + C_{V_{\_Low}}\right) + \left(C_{L2} + C_{S2} + C_{V_{\_Low}}\right)}$$

$$C_{High} = \frac{\left(C_{L1} + C_{S1} + C_{V\_High}\right) \cdot \left(C_{L2} + C_{S2} + C_{V\_High}\right)}{\left(C_{L1} + C_{S1} + C_{V\_High}\right) + \left(C_{L2} + C_{S2} + C_{V\_High}\right)}$$

- C<sub>Low</sub> is the effective capacitance due to the low varactor capacitance, load capacitance and stray capacitance.
   C<sub>Low</sub> determines the high frequency component on the TPR.
- $C_{High}$  is the effective capacitance due to the high varactor capacitance, load capacitance and stray capacitance.  $C_{High}$  determines the low frequency component on the TPR.

Total Pull Range (TPR) = 
$$\frac{1}{2 \cdot \frac{C_0}{C_1} \cdot \left(1 + \frac{C_{Low}}{C_0}\right)} - \frac{1}{2 \cdot \frac{C_0}{C_1} \cdot \left(1 + \frac{C_{High}}{C_0}\right)} \cdot 10^6$$

Absolute Pull Range (APR) = Total Pull Range - (Frequency Tolerance + Frequency Stability + Aging)

#### **EXAMPLE CALCULATIONS**

Using the tables and figures above, we can now calculate the TPR and APR of the VCXO using the example crystal parameters. For the numerical example below there were some assumptions made. First, the stray capacitance ( $C_{\rm S1}$ ,  $C_{\rm S2}$ ), which is all the excess capacitance due to board parasitic, is 4pF. Second, the expected lifetime of the project is 5 years; hence the inaccuracy due to

aging is  $\pm 15$ ppm. Third, though many boards will not require load tuning capacitors ( $C_{L1}$ ,  $C_{L2}$ ), it is recommended for long-term consistent performance of the system that two tuning capacitor pads be placed into every design. Typical values for the load tuning capacitors will range from 0 to 4pF.

$$C_{Low} = \frac{\left(0 + 4\,pf + 15.4\,pf\right)\cdot\left(0 + 4\,pf + 15.4\,pf\right)}{\left(0 + 4\,pf + 15.4\,pf\right) + \left(0 + 4\,pf + 15.4\,pf\right)} = 9.7\,pf$$

$$C_{High} = \frac{\left(0 + 4pf + 29.6pf\right) \cdot \left(0 + 4pf + 29.6pf\right)}{\left(0 + 4pf + 29.6pf\right) + \left(0 + 4pf + 29.6pf\right)} = 16.8pf$$

$$TPR = \left(\frac{1}{2 \cdot 220 \cdot \left(1 + \frac{9.7 \, pF}{4 \, pF}\right)} - \frac{1}{2 \cdot 220 \cdot \left(1 + \frac{16.8 \, pF}{4 \, pF}\right)}\right) \cdot 10^6 \cdot = 226.5 \, ppm$$

 $TPR = \pm 113.25ppm$ 

 $APR = 113.25ppm - (20ppm + 20ppm + 15ppm) = \pm 58.25ppm$ 

The example above will ensure a total pull range of  $\pm 113.25$  ppm with an APR of  $\pm 58.25$ ppm. Many times, board designers may select their own crystal based on their application. If the application requires a tighter APR, a crystal

with better pullability (C0/C1 ratio) can be used. Also, with the equations above, one can vary the frequency tolerance, temperature stability, and aging or shunt capacitance to achieve the required pullability.

#### RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

#### INPUTS:

#### **OUTPUTS:**

#### CONTROL PINS:

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A  $1k\Omega$  resistor can be used. The VC pin can not be floated.

#### LVCMOS OUTPUT:

All unused LVCMOS output can be left floating. We recommend that there is no trace attached.

#### SCHEMATIC EXAMPLE

Figure 2 shows an example of ICS81006l application schematic. The decoupling capacitors should be located as close as possible to the power pin. For the LVCMOS  $20\Omega$  output drivers,

series termination example is shown in the schematic. Additional termination approaches are shown in the LVCMOS Termination Application Note.

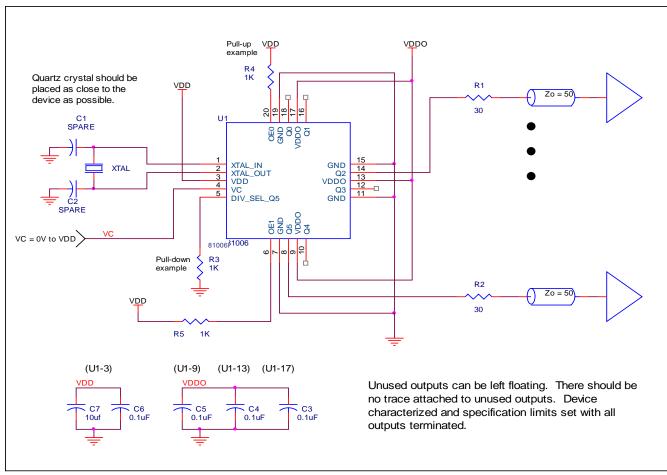


FIGURE 2. ICS81006I SCHEMATIC EXAMPLE

#### VFQFN EPAD THERMAL RELEASE PATH

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in *Figure 3*. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as "heat pipes". The number of vias (i.e. "heat pipes")

are application specific and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mils (0.30 to 0.33mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/ slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a guideline only. For further information, refer to the Application Note on the Surface Mount Assembly of Amkor's Thermally/ Electrically Enhance Leadfame Base Package, Amkor Technology.

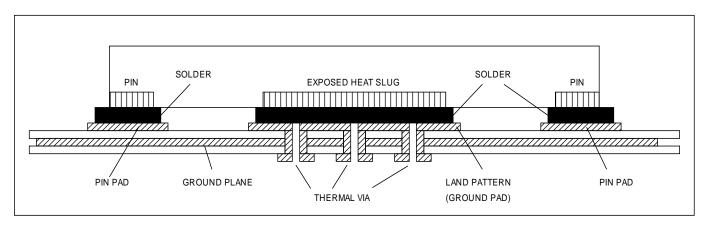


FIGURE 3. P.C.ASSEMBLY FOR EXPOSED PAD THERMAL RELEASE PATH -SIDE VIEW (DRAWING NOT TO SCALE)

# RELIABILITY INFORMATION

Table 7.  $\theta_{\text{\tiny JA}}$  vs. Air Flow Table for 20 Lead VFQFN

 $\theta_{_{JA}}$  by Velocity (Meters per Second)

0

1

3

Multi-Layer PCB, JEDEC Standard Test Boards

60.4°C/W

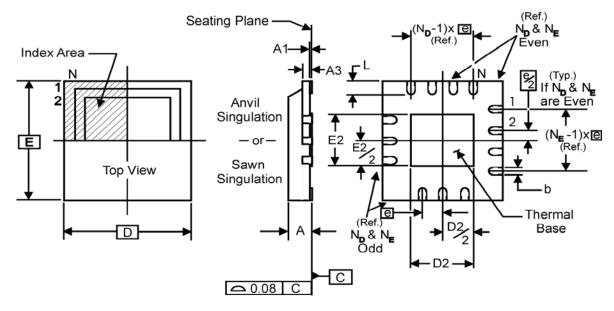
52.8°C/W

46.0°C/W

#### TRANSISTOR COUNT

The transistor count for ICS81006I is: 983

#### PACKAGE OUTLINE - K SUFFIX FOR 20 LEAD VFQFN



NOTE: The following package mechanical drawing is a generic drawing that applies to any pin count VFQFN package. This drawing is not intended to convey the actual pin count or pin layout of

this device. The pin count and pinout are shown on the front page. The package dimensions are in Table 6 below.

TABLE 8. PACKAGE DIMENSIONS FOR 20 LEAD VFQFN

	JEDEC VARIATION					
ALL DIMENSIONS IN MILLIMETERS						
SYMBOL	MINIMUM	MAXIMUM				
N	20					
Α	0.80	1.0				
A1	0	0.05				
А3	0.25 Reference					
b	0.18	0.30				
е	0.50 BASIC					
N <sub>D</sub>	5					
N <sub>E</sub>	5					
D	4.0					
D2	0.75	2.80				
E	4.0					
E2	0.75	2.80				
L	0.35	0.75				

Reference Document: JEDEC Publication 95, MO-220

TABLE 9. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
81006AKI	1006AI	20 lead VFQFN	tube	-40°C to 85°C
81006AKIT	1006AI	20 lead VFQFN	2500 tape & reel	-40°C to 85°C
81006AKILF	006AIL	20 lead "Lead-Free" VFQFN	tube	-40°C to 85°C
81006AKILFT	006AIL	20 lead "Lead-Free" VFQFN	2500 tape & reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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	REVISION HISTORY SHEET					
Rev	Table	Page	Description of Change	Date		
		1	General Description and Features section changed output frequency max. from 40MHz to 31.25MHz.			
В	T4A - T4D	4-5 6	AC Tables - changed output frequency from 40MHz max. to 31.25MHz max. Added Phase Noise Plot.	10/8/08		
	T9	15	Ordering Information Table - added lead-free marking			

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